

L Number	Hits	Search Text	DB	Time stamp
1	973	(non adj volatile) and (select adj transistor)	USPAT; EPO; JPO; DERWENT; USOCR	2003/08/20 12:26
2	662	((non adj volatile) and (select adj transistor)) and well	USPAT; EPO; JPO; DERWENT; USOCR	2003/08/20 12:26
3	549	((non adj volatile) and (select adj transistor)) and well) and substrate	USPAT; EPO; JPO; DERWENT; USOCR	2003/08/20 12:26
4	143	((non adj volatile) and (select adj transistor)) and well) and substrate) and biasing	USPAT; EPO; JPO; DERWENT; USOCR	2003/08/20 12:27
5	101	((non adj volatile) and (select adj transistor)) and well) and substrate) and biasing) and (word adj line)	USPAT; EPO; JPO; DERWENT; USOCR	2003/08/20 12:27
6	68	((non adj volatile) and (select adj transistor)) and well) and substrate) and biasing) and (word adj line)) and block	USPAT; EPO; JPO; DERWENT; USOCR	2003/08/20 12:35
7	106	((non adj volatile) and (select adj transistor)) and well) and substrate) and (365/185.18.ccls.)	USPAT; EPO; JPO; DERWENT; USOCR	2003/08/20 12:35